1. Scope

The present specifications shall apply to Sanken silicon diode, RU3M.

2. Outline

Туре	Silicon Diode (Mesa Type)		
Structure	Resin Molded	Flammability:UL94-V0(Equivalent)	
Applications	Pulse Rectification, etc.		

3. Absolute maximum ratings

No.	Item	Symbol	Unit	Rating	Conditions
1 Transient Peak Reverse Voltage		V _{RSM}	V	450	
2	Peak Reverse Voltage	V _{RM}	V	400	
3	Average Forward Current	$I_{F(AV)}$	А	1.5	Refer to Derating of 5
4	Peak Surge Forward Current	I _{FSM}	А	50	10msec. Half sinewave, one shot
5	Junction Temperature	T_j	°C	-40~+150	
6	Storage Temperature	T _{stg}	°C	-40~+150	

4. Electrical characteristics (Ta=25°C, unless otherwise specified)

No.	No. Item		Unit	Value	Conditions
1	1 Forward Voltage Drop		V	1.1 max.	I _F =1.5A
2	2 Reverse Leakage Current		μΑ	10 max.	V _R =V _{RM}
3 Reverse Leakage Current Under High Temperature		H∙I _R	μΑ	350 max.	V _R =V _{RM} , T _j =100°C
4	4 Reverse Recovery Time		μs	0.4 max.	$I_{F}=I_{RP}=1^{\circ}C 0mA,$ Ta=25°C 90% Recovery point
4	Reverse Recovery Time	Trr-2	μs	0.18 max.	I_F =10mA, I_{RP} =20mA, Ta=25°C 75% Recovery point
5	Thermal Resistance	$R_{th(j-l)}$	°C /W	12 max.	Between Junction and Lead



6-1 Package type, physical dimensions and material



Dimensions in mm

*1 The allowance position of Body against the center of whole lead wire is 0.5mm(max.)

*2 The centric allowance of lead wire against center of physical body is 0.3mm(max.)

*3 The burr may exit up to 2mm from the body of lead

6-2 Appearance

The body shall be clean and shall not bear any stain, rust or flaw.

6-3 Marking

Cathode Band			
1	1		
2 3	2 3		

The Type number and Lot number are to be marked in red.

① Type number RU3M

- ② Lot number 1 First digit: Last digit of Year Second digit: Month From 1 to 9 for Jan. to Sep. O for Oct., N for Nov., and D for Dec.
- 3 Lot number 2 (ten days)
 - Top of the month Middle of month • :
 - •• :
 - . . . : End of month